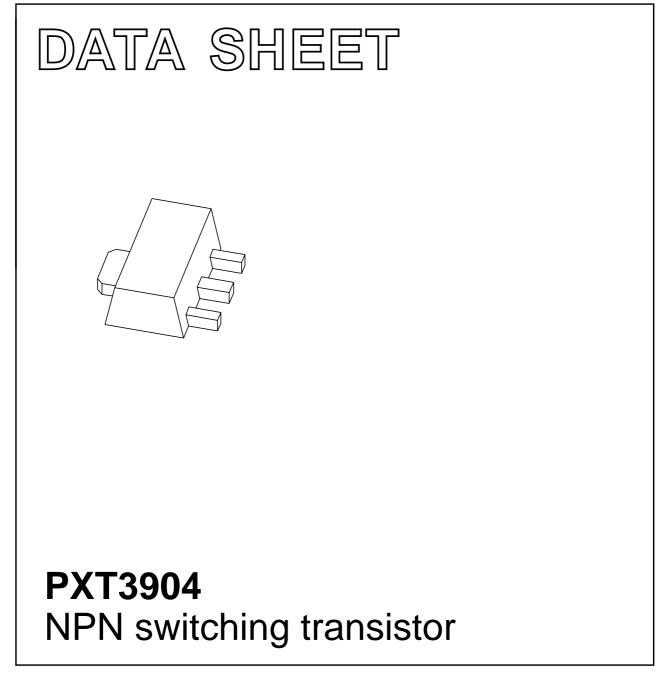
# DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 1999 Apr 14 2004 Nov 22



HILIP

**PXT3904** 

## NPN switching transistor

#### FEATURES

- Low current (max. 100 mA)
- Low voltage (max. 40 V).

#### APPLICATIONS

• High-speed switching.

#### DESCRIPTION

NPN switching transistor in a SOT89 plastic package. PNP complement: PXT3906.

#### MARKING

TYPE NUMBER	MARKING CODE <sup>(1)</sup>	
PXT3904	*1A	

#### Note

- 1. \* = p: Made in Hong Kong.
  - \* = t: Made in Malaysia.

\* = W: Made in China.

### **ORDERING INFORMATION**

#### PINNING

PIN	DESCRIPTION	
1	emitter	
2	collector	
3	base	

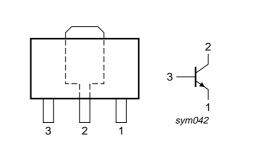


Fig.1 Simplified outline (SOT89) and symbol.

	PACKAGE			
ITFE NUMBER	NAME DESCRIPTION VER			
PXT3904	SC-62	plastic surface mounted package; collector pad for good heat transfer; 3 leads	SOT89	

### PXT3904

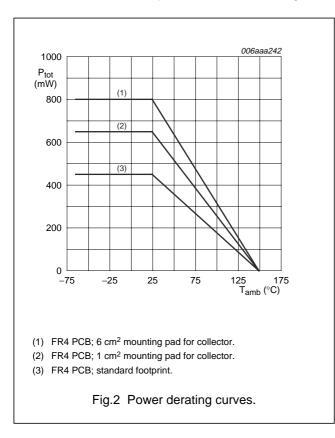
#### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS		MAX.	UNIT	
V <sub>CBO</sub>	collector-base voltage	open emitter	-	60	V	
V <sub>CEO</sub>	collector-emitter voltage	open base	_	40	V	
V <sub>EBO</sub>	emitter-base voltage	open collector	-	6	V	
I <sub>C</sub>	collector current (DC)		_	100	mA	
I <sub>CM</sub>	peak collector current		-	200	mA	
I <sub>BM</sub>	peak base current		-	100	mA	
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$				
		note 1	-	0.45	W	
		note 2	-	0.65	W	
		note 3	-	0.8	W	
T <sub>stg</sub>	storage temperature		-65	+150	°C	
Tj	junction temperature		-	150	°C	
T <sub>amb</sub>	ambient temperature		-65	+150	°C	

#### Notes

- 1. Device mounted on a printed-circuit board, single-sided copper, tin-plated and standard footprint.
- 2. Device mounted on a printed-circuit board, single-sided copper, tin-plated and mounting pad for collector 1 cm<sup>2</sup>.
- 3. Device mounted on a printed-circuit board, single-sided copper, tin-plated and mounting pad for collector 6 cm<sup>2</sup>.



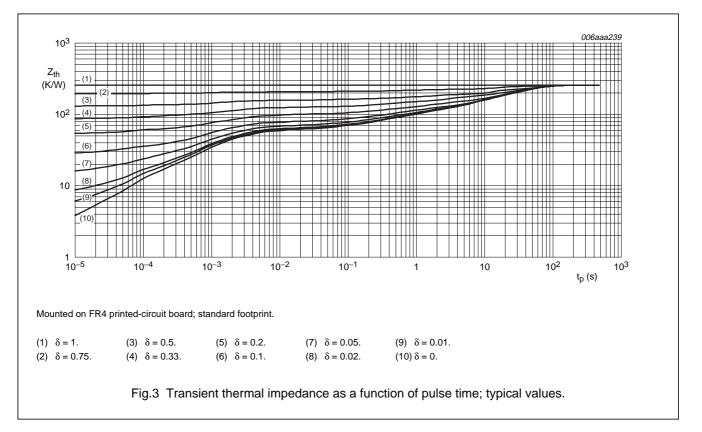
### PXT3904

### THERMAL CHARACTERISTICS

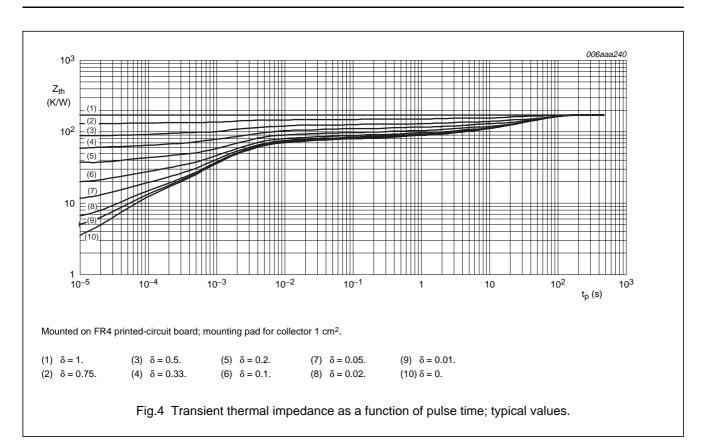
SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th(j-a)</sub>	thermal resistance from junction to	in free air		
	ambient	note 1	278	K/W
		note 2	192	K/W
		note 3	156	K/W
R <sub>th(j-s)</sub>	thermal resistance from junction to soldering point		80	K/W

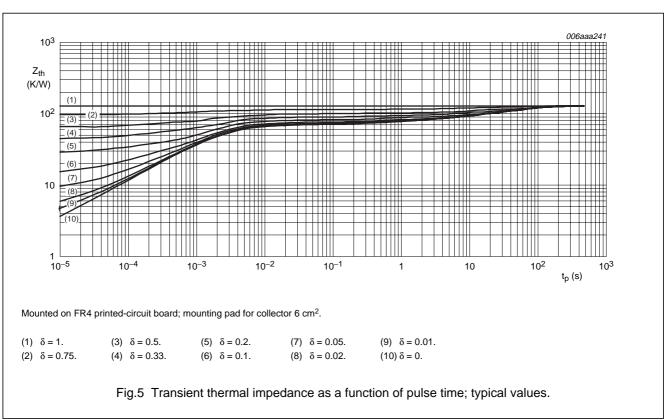
#### Notes

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### PXT3904



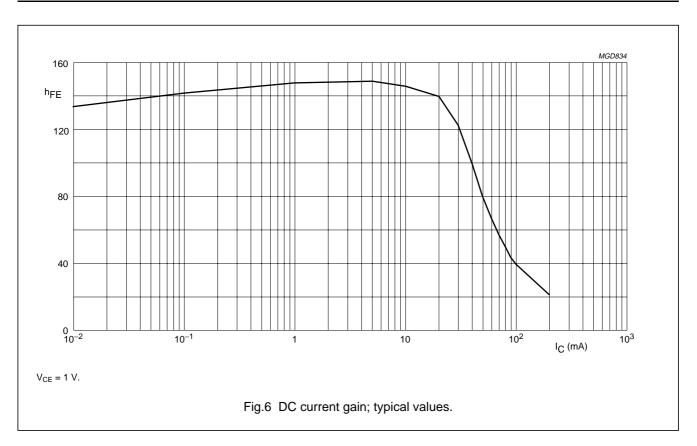


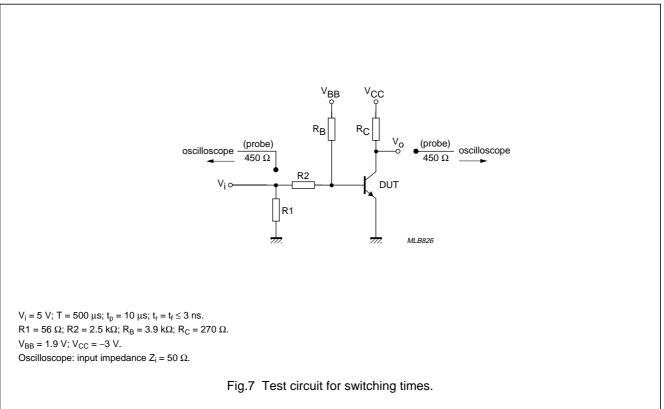
### PXT3904

### CHARACTERISTICS

 $T_{amb}$  = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I <sub>CBO</sub>	collector-base cut-off current	I <sub>E</sub> = 0 A; V <sub>CB</sub> = 30 V	-	50	nA
I <sub>EBO</sub>	emitter-base cut-off current	$I_{C} = 0 \text{ A}; V_{EB} = 6 \text{ V}$	-	50	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 1 V; (see Fig.6)			
		I <sub>C</sub> = 0.1 mA	60	-	
		$I_{\rm C} = 1  \rm{mA}$	80	-	
		I <sub>C</sub> = 10 mA	100	300	
		I <sub>C</sub> = 50 mA	60	-	
		I <sub>C</sub> = 100 mA	30	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	I <sub>C</sub> = 10 mA; I <sub>B</sub> = 1 mA	-	200	mV
		$I_{\rm C} = 50 \text{ mA}; I_{\rm B} = 5 \text{ mA}$	_	200	mV
V <sub>BEsat</sub>	base-emitter saturation voltage	I <sub>C</sub> = 10 mA; I <sub>B</sub> = 1 mA	650	850	mV
		$I_{\rm C} = 50 \text{ mA}; I_{\rm B} = 5 \text{ mA}$	-	950	mV
Cc	collector capacitance	$I_E = i_e = 0 \text{ A}; V_{CB} = 5 \text{ V}; f = 1 \text{ MHz}$	_	4	pF
C <sub>e</sub>	emitter capacitance	$I_{C} = i_{c} = 0 \text{ A}; V_{EB} = 500 \text{ mV};$ f = 1 MHz	-	8	pF
f <sub>T</sub>	transition frequency	I <sub>C</sub> = 10 mA; V <sub>CE</sub> = 20 V; f = 100 MHz	300	-	MHz
F	noise figure	$I_{C}$ = 100 μA; V <sub>CE</sub> = 5 V; R <sub>S</sub> = 1 kΩ; f = 10 Hz to 15.7 kHz	-	5	dB
Switching t	imes (between 10% and 90% levels)	; (see Fig.7)	•		
t <sub>on</sub>	turn-on time	I <sub>Con</sub> = 10 mA; I <sub>Bon</sub> = 1 mA;	-	65	ns
t <sub>d</sub>	delay time	I <sub>Boff</sub> = –1 mA	-	35	ns
t <sub>r</sub>	rise time	1	-	35	ns
t <sub>off</sub>	turn-off time	1	-	240	ns
ts	storage time	1	-	200	ns
t <sub>f</sub>	fall time	1	-	50	ns

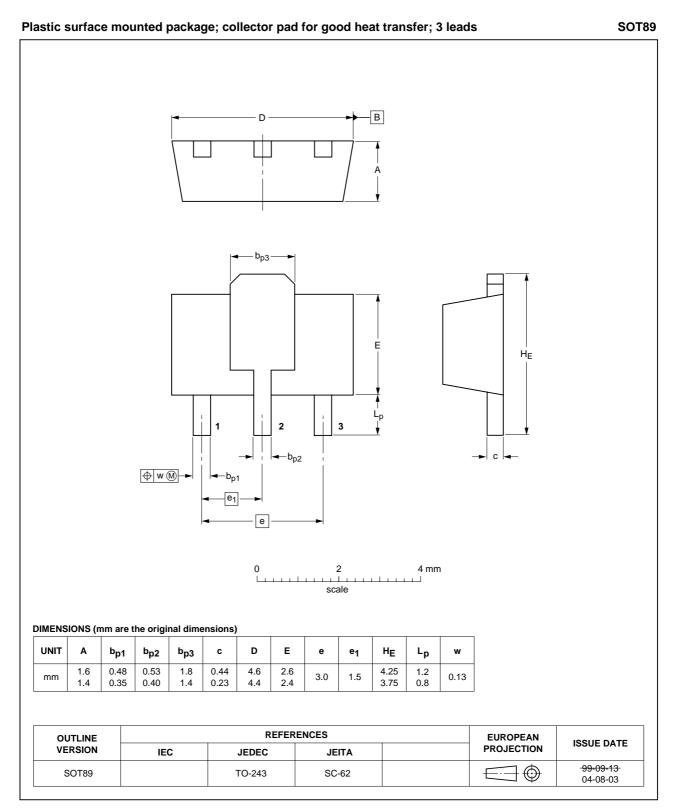




### PXT3904

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### PACKAGE OUTLINE



PXT3904

#### DATA SHEET STATUS

LEVEL	DATA SHEET STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)(3)</sup>	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

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